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October 2001

FDC6401N

SEMICONDUCTOR IM

Dual N-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

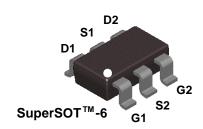
This Dual N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

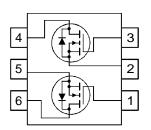
Applications

- DC/DC converter
- Battery Protection
- Power Management

Features

- 3.0 A, 20 V. $R_{DS(ON)} = 70 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$ $R_{DS(ON)} = 95 \text{ m}\Omega @ V_{GS} = 2.5 \text{ V}$
- Low gate charge (3.3 nC)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Sourc	e Voltage		20	V
V _{GSS}	Gate-Source Voltage			±12	V
I _D	Drain Currer	nt – Continuous	(Note 1a)	3.0	A
	– Pulsed			12	
P _D	Power Dissi	pation for Single Operation	(Note 1a)	0.96	W
			(Note 1b)	0.9	
			(Note 1c)	0.7	
T _J , T _{STG}	Operating a	nd Storage Junction Tempe	rature Range	-55 to +150	°C
Therma	I Charact	eristics			
R _{0JA}	Thermal Resistance, Junction-to-Ambient		nt (Note 1a)	130	°C/W
R _{eJC}	Thermal Res	sistance, Junction-to-Case	(Note 1)	60	°C/W
Packag	e Marking	g and Ordering In	formation		
Device Marking		Device	Reel Size	Tape width	Quantity
.401		FDC6401N	7"	8mm	3000 units

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FDC6401N

	cal Characteristics	$T_A = 25^{\circ}C$ unless otherwise noted	•		-	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics				•	
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_D = 250 \mu\text{A}$	20			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		13		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current $V_{DS} = 16 V$, $V_{GS} = 0 V$				1	μΑ
I _{GSSF}	Gate–Body Leakage, Forward $V_{GS} = 12 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -12 \text{ V} \qquad V_{DS} = 0 \text{ V}$			100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	0.5	0.9	1.5	V
<u>ΔVGS(th)</u> ΔTJ	Gate Threshold Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		-3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 4.5 \ V, & I_D = 3.0 \ A \\ V_{GS} = 2.5 \ V, & I_D = 2.5 \ A \\ V_{GS} = 4.5 \ V, & I_D = 3.0 \ A, T_J = 125^\circ C \end{array} $		50 66 71	70 95 106	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 4.5 \text{ V}, V_{DS} = 5 \text{ V}$	12			Α
g _{FS}	Forward Transconductance	$V_{DS} = 5V$, $I_{D} = 3.0 \text{ A}$		10		S
Dynamic	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$		324		pF
Coss	Output Capacitance	f = 1.0 MHz		82		pF
C _{rss}	Reverse Transfer Capacitance			42		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 10 \text{ V}, \qquad I_D = 1 \text{ A},$		5	10	ns
tr	Turn–On Rise Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		7	14	ns
t _{d(off)}	Turn–Off Delay Time			13	23	ns
t _f	Turn–Off Fall Time			1.6	3	ns
Q _g	Total Gate Charge	$V_{DS} = 10 V, \qquad I_D = 3.0 A,$		3.3	4.6	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 4.5 V$	V _{GS} = 4.5 V			nC
Q _{gd}	Gate-Drain Charge			0.7		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source				0.8	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 0.8 A$ (Note 2)		0.7	1.2	V

 R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a) 130 °C/W when mounted on a 0.125 in² pad of 2 oz. copper.

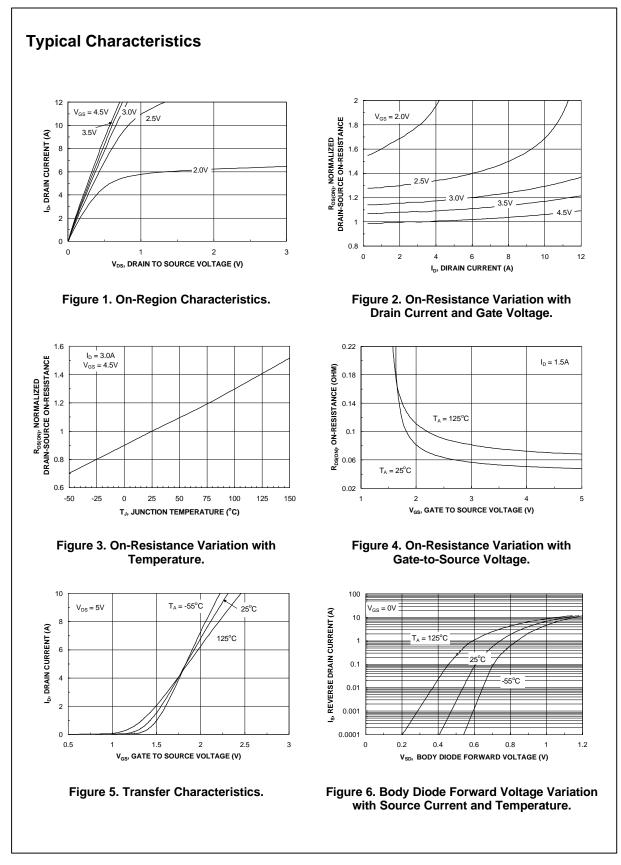


 b) 140 °C/W when mounted on a .004 in² pad of 2 oz copper

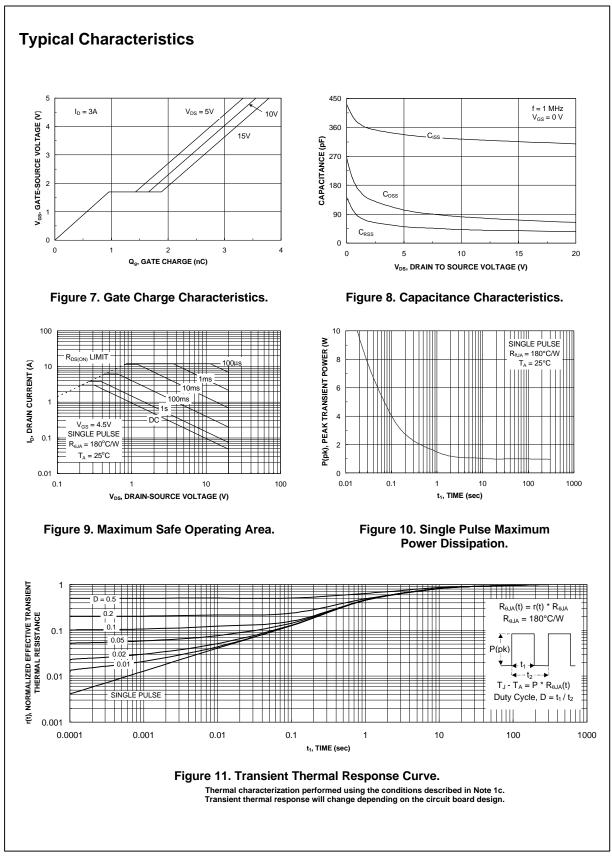
c) 180 C°/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%



FDC6401N



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